# Performance of a silicon PIN photodiode based radon

detector for low radioactivity environment

## Kyungmin Seo<sup>a,b</sup> a. Sejong University,

**Center for Underground Physics** 

It is very important to monitor the amount of radon (Rn-222) in the underground experiments with ultra low background requirements. The radioactivity from the radon can be a significant background source to the experiments and need to be measured precisely. We have upgraded a radon detector with a volume of ~70 L which was used in the KIMS (Korean Invisible Matter Search) experiment by replacing with a Hamamatsu silicon PIN photodiode and a Hamamatsu pre-amplifier. The positively charged radon's daughter particles (Po-214 and Po-218 mostly) produced in the air of the detector chamber are collected by the photodiode in a negative high voltage. The energy resolutions of alpha particles emitted from the decays of the daughter particles are measured to be identified. We also have had about 3 months of data with the air sealed after closing the chamber. The half-lifetimes of Rn-222 from two daughter particles measured together with the background level of the chamber are going to be presented.

b. Center for Underground Physics, IBS

### 1. Introduction Radon detection process Radium PIN photodiode <sup>214</sup>Po<sup>+</sup> <sup>212</sup>Po<sup>+</sup> Astatine <sup>214</sup>Po+ Polonium Electric field <sup>218</sup>Po<sup>+</sup> Bismuth <sup>218</sup>Po<sup>+</sup> Lead Thallium Mercury Radon detector system flow chart Power Supply Flowmeter Power line Power Supply

Equipment

Signal line

Control line

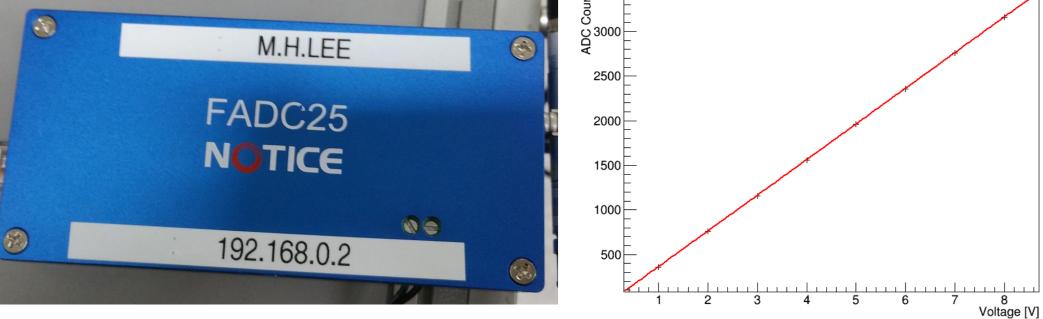


HV supply & Shaping amplifier in a NIM crate

Radon chamber

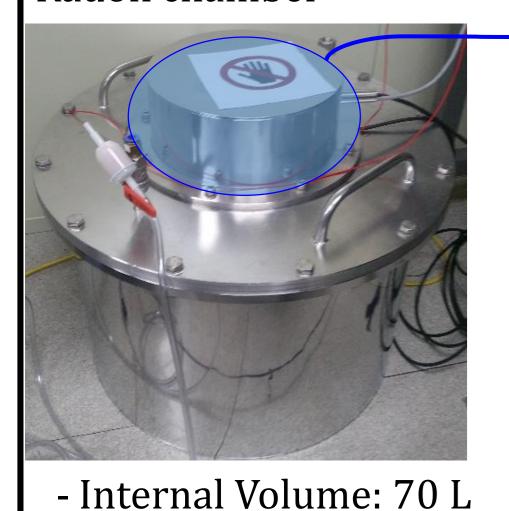


Flash ADC 25



- Standalone 1 channel FADC
- 25 MS/s sampling rate, 12 bit resolution
- $-0\sim10 \text{ V}$  input range (modified from 4 V)
- Data buffer for 130 k samples

Radon chamber



- High Voltage: -1,000 V

- Stainless steel with electro

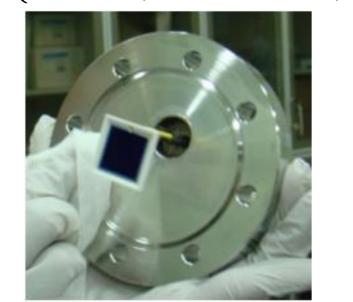
polished inside surface

- Bias: 30 V

HV divider circuit & preamp (H4083, Hamamatsu)

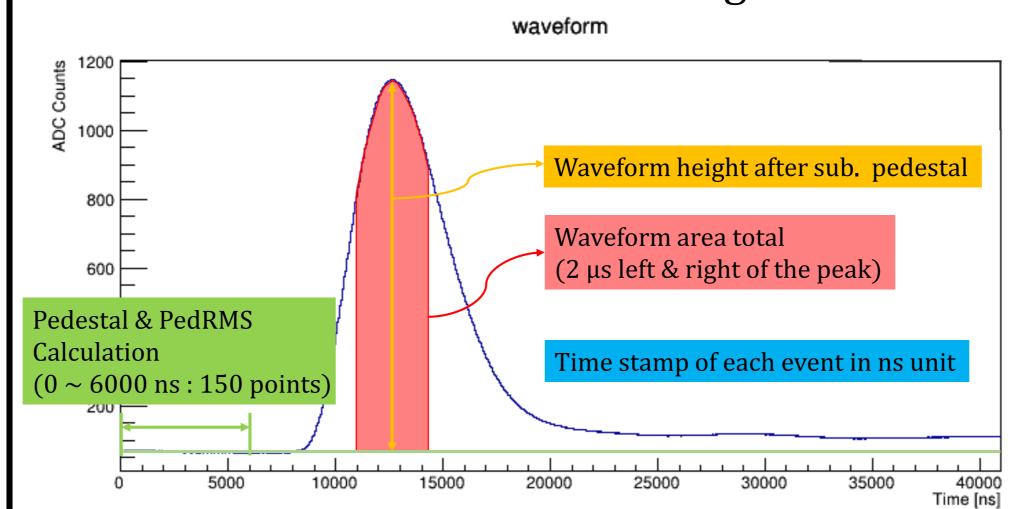


Silicon PIN photodiode (S3204-9,  $18 \times 18 \text{ mm}^2$ , Hamamatsu)



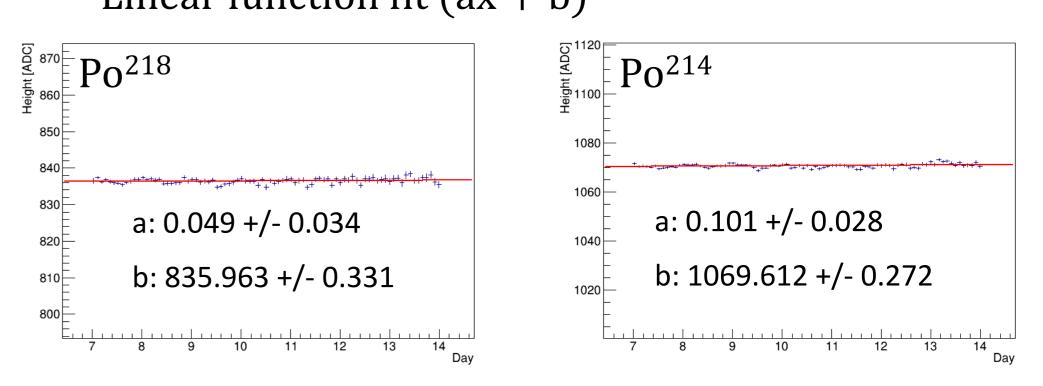
#### 2. Waveform

FADC25 waveform from an  $\alpha$  signal



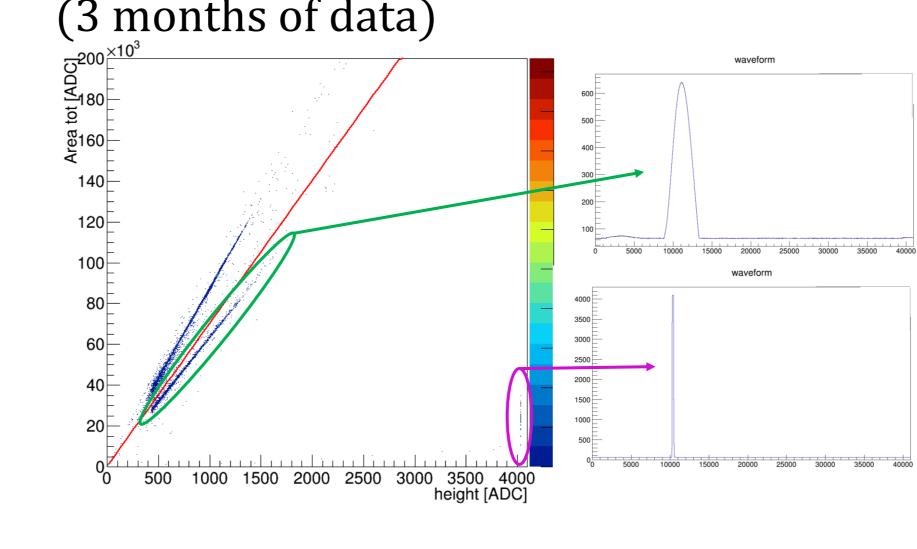
## 5. Stability check

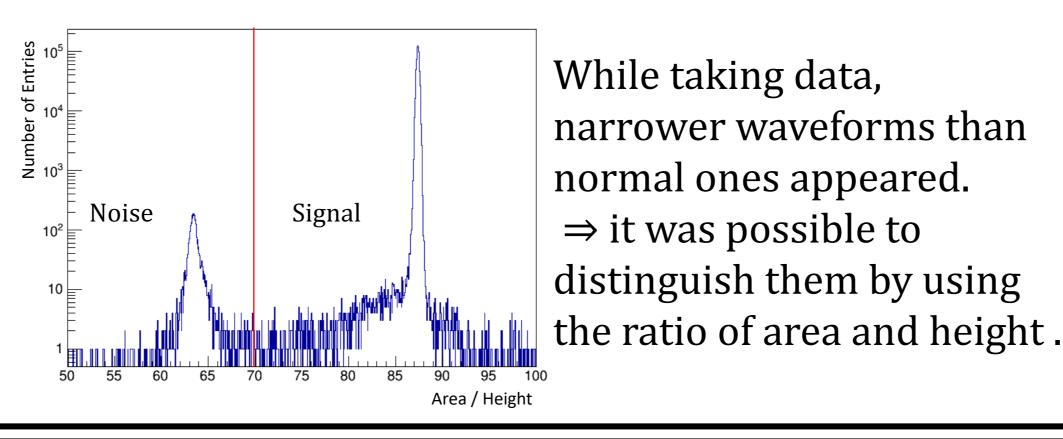
- Profiles of Po<sup>214</sup> & Po<sup>218</sup> with time
  - Selected within 2 sigma region
  - Linear function fit (ax + b)



## 3. Noise rejection

Area total & Waveform height distribution (3 months of data)

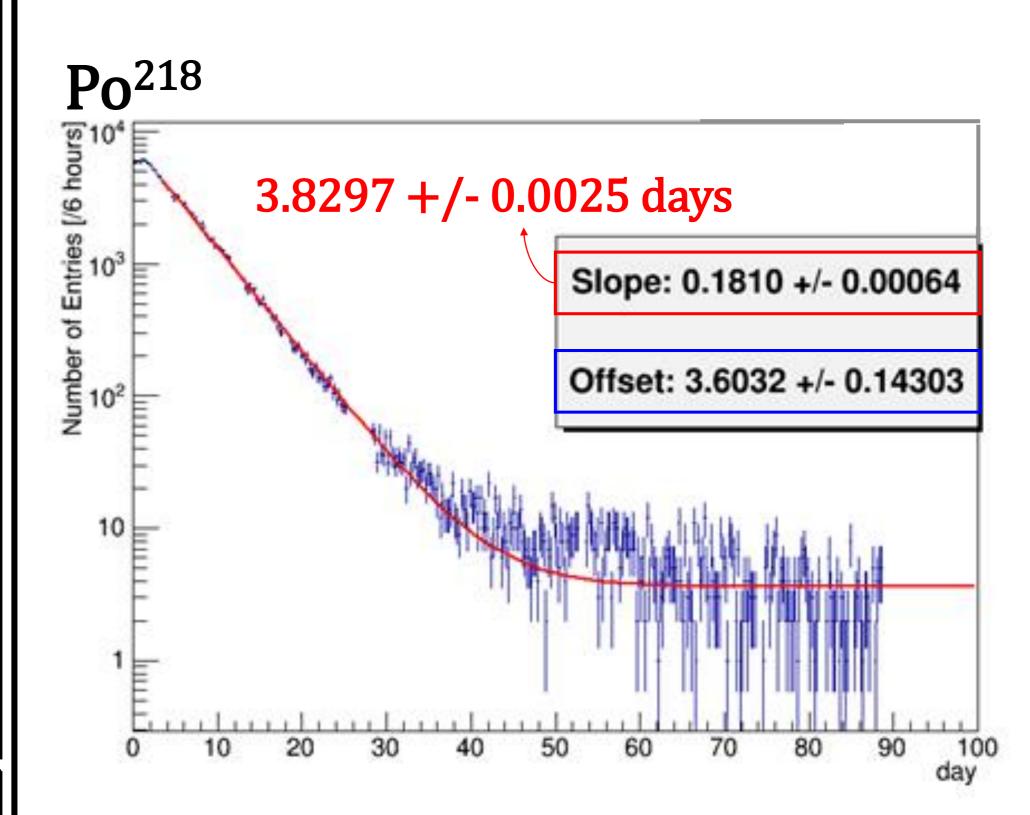




## Measured the half lifetime of Rn<sup>222</sup> using Po<sup>214</sup> &

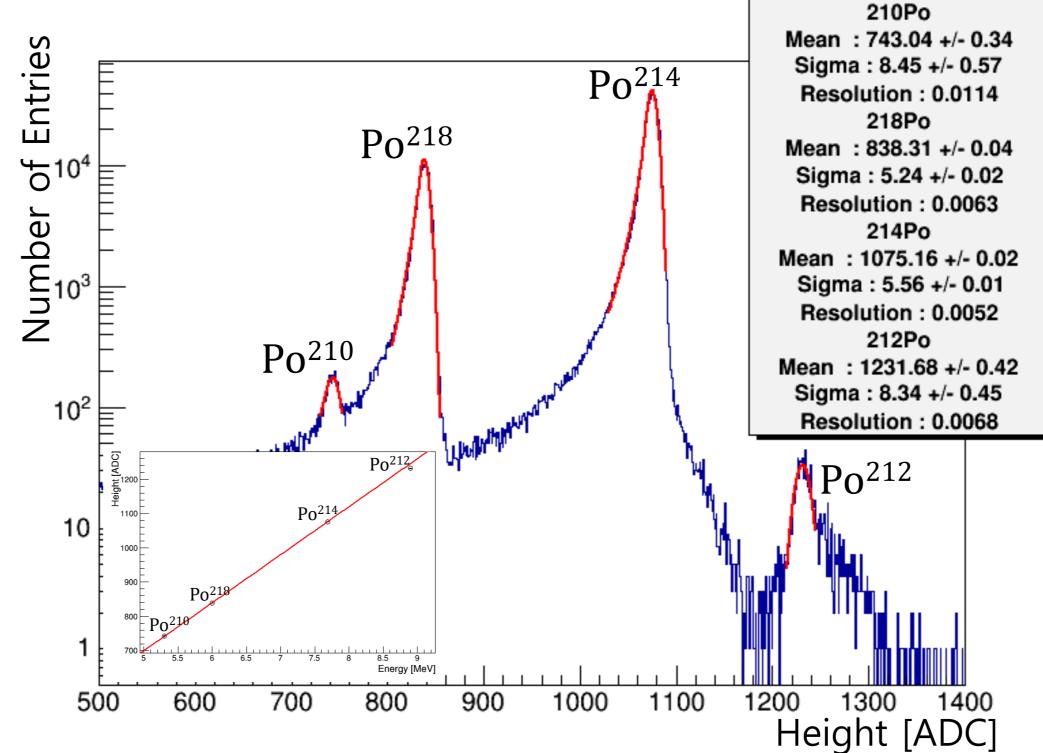
6. Half lifetime measurements

- Po<sup>218</sup> events (within 2 sigma)
  - $T_{1/2}$  (NNDC): 3.8235(3)days NNDC: National Nuclear Data Center
  - Fitting function:  $ae^{-bt} + c$

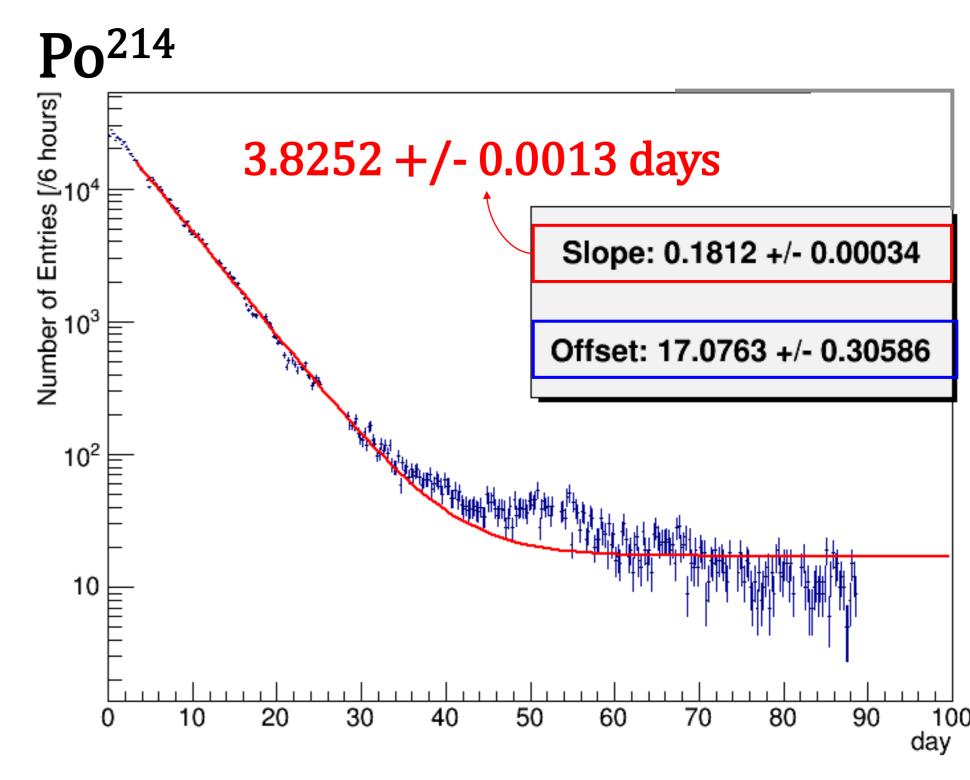


## 4. Pulse height distribution

Height distribution using data of 3 months



- Crystal ball function is used for fitting of all peaks.
- (sigma) Resolution is less than or equal to 1% for each peaks.
- 4 peaks from  $Po^{210}$ ,  $Po^{218}$ ,  $Po^{214}$  and  $Po^{212}$  show a good energy linearity.



- The background level obtained from the offset is  $\sim \frac{1}{2000} \times \text{max}$
- Radon concentration of the initial air: 150 Bq/m<sup>3</sup> (RAD7)
- $\Rightarrow$  0.075 Bq/m<sup>3</sup> BKG level

### 7. Summary

- > The upgraded radon chamber has stably collected data for 90 days after sealing an office air.
- > Noise events were removed effectively using a waveform area and height ratio parameter.
- From the 90 days data, 4 radon daughters (Po<sup>210</sup>, Po<sup>218</sup>, Po<sup>218</sup>, and Po<sup>212</sup>) were observed and a good energy linearity among them was confirmed.
- $\succ$  The half lifetime of Rn<sup>222</sup> using Po<sup>214</sup> and Po<sup>218</sup> was measure to be 3.8252 days and 3.8297 days, respectively. They are within 2.5 sigma of the Rn<sup>222</sup> half lifetime from NNDC.
- $\succ$  The background level of this radon chamber is estimated as ~75 mBq/m<sup>3</sup>.